2SC5418

Silicon NPN triple diffusion mesa type

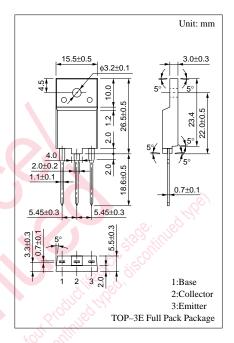
For horizontal deflection output

Features

- High breakdown voltage, and high reliability through the use of a glass passivation layer
- High-speed switching
- Wide area of safe operation (ASO)

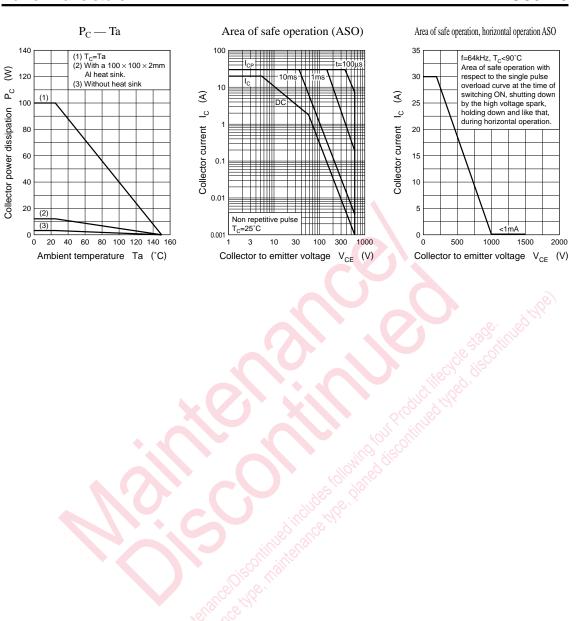
| Parameter | Symbol | Symbol Ratings | | |
|-----------------------------------|------------------|----------------|----|--|
| Collector to base voltage | V _{CBO} | 1700 | V | |
| | V _{CES} | 1700 | V | |
| Collector to emitter voltage | V _{CEO} | 600 | V | |
| Emitter to base voltage | V _{EBO} | 5 | V | |
| Peak collector current | I _{CP} | 30 | А | |
| Collector current | I _C | 20 | А | |
| Base current | IB | 10 | А | |
| Collector power $T_C=25^{\circ}C$ | | 100 | | |
| dissipation Ta=25°C | P _C | 3.5 | W | |
| Junction temperature | Tj | 150 | °C | |
| Storage temperature | T _{stg} | -55 to +150 | °C | |

Absolute Maximum Ratings $(T_c=25^{\circ}C)$



Electrical Characteristics $(T_c=25^{\circ}C)$

| Parameter | Symbol | Conditions | min | typ | max | Unit |
|---|----------------------|---|-----|-----|-----|------|
| Collector cutoff current | I _{CBO} | $V_{CB} = 1000V, I_E = 0$ | | | 50 | μΑ |
| | | $V_{CB} = 1700 V, I_E = 0$ | | | 1 | mA |
| Emitter cutoff current | I _{EBO} | $V_{\rm EB} = 5V, I_{\rm C} = 0$ | | | 50 | μA |
| Forward current transfer ratio | h _{FE} | $V_{CE} = 5V, I_{C} = 10A$ | 7 | | 14 | |
| Collector to emitter saturation voltage | V _{CE(sat)} | $I_{\rm C} = 10A, I_{\rm B} = 2.8A$ | | | 3 | V |
| Base to emitter saturation voltage | V _{BE(sat)} | $I_{\rm C} = 10$ A, $I_{\rm B} = 2.8$ A | | | 1.5 | v |
| Transition frequency | f _T | $V_{CE} = 10V, I_C = 0.1A, f = 0.5MHz$ | | 3 | | MHz |
| Storage time | t _{stg} | $I_{\rm C} = 12$ A, $I_{\rm B1} = 2.4$ A, $I_{\rm B2} = -4.8$ A | | | 4.0 | μs |
| Fall time | t _f | | | | 0.3 | μs |



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